W orkshop on Integrable T heories, Solitons and D uality

## C onductance from N on-perturbative M ethods I

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#### Abstract

W\) e investigate di erent $m$ ethods to com pute the $D C$ conductance in a quantum $w$ ire doped w ith som e im puritied by exploiting the integrability of the theories under consideration. As an essential ingredient in all $m$ ethods we evaluate the re ection and transm ission am plitudes of the im purities for a variety of defects. $W$ hen the im purities in the w ire are coupled to an extemal three dim ensionallaser eld, we predict the generation of harm onic em ission spectra. W e propose a m odi ed version of the well-known K ubo formula, which inconporates the im purities of the system and evaluate the current-current two-point correlation function it involves w ith the help of a form factor expansion. A com parison w ith the corresponding quantities com puted in a Landauer transport theory picture is carried out in part II.


 em phasis on the rst two. O lalla C astro-A lvaredo will present the second part of this talk.

1. G eneralities on conductance

In the context of $1+1$ dim ensional quantum eld theories an im pressive arsenal of nonperturbative techniques has been developed over the last 25 years. $T$ he originalm otivation w as to use the low er dim ensionalset up as a testing ground for general conceptual ideas and possibly to apply them in the context of string theory, such that m ost of the work in this area can be characterized very often as rather form al. H ow ever, lately the experim ental techniques have advance to such an extent that one $m$ ight realistically hope to $m$ easure various quantities which can be predicted based on these approaches.

O ne of those quantities, which is particularly easy to access, is the conductance (conductivity). It can be $m$ easured in general directly $w$ ithout perturbing very $m$ uch the behaviour of the system, e.g. a rigid-lattice bulk $m$ etal, such that the uncertainty of experim ental artefacts is reduced to a $m$ in im um. Indeed, there have been som e fairly recent

Speaker.
$m$ easurem ents $\left[\overline{[ }_{1}\right]$ of this quantity in $1+1$ dim ensions and the challenge is of course to explain these data theoretically and possibly inspire $m$ ore experim ents of a sim ilar type.

There exist tw o m ain theoretical descriptions to com pute the conductance, the $\mathrm{K} u$ uo form ula $\left[\begin{array}{l}-1,1 \\ \hline\end{array}\right]$, which is the outcom e of dynam icallinear-response theory and the LandauerButtinger theory [1] work I want to present is a com parison betw een these tw o descriptions by em ploying nonperturbative $m$ ethods of $1+1$ dim ensionalintegrable $m$ odels. It is in th is sense the w ording non-perturbative is to be understood, that is despite the fact that the overall theoretical description is of a perturbative nature, w ithin these fram ew orks we use non-perturbative $m$ ethods. I will concentrate on our proposal of a generalized $K u b o$ form ula and in the second part, presented by O lalla C astro-A lvaredo, the com putations w ithin the LandauerB uttinger transport theory fram ew ork w illbe presented.

I w ill start by anticipating the quantities we have to com pute. The system we consider is a one dim ensionalquantum $w$ ire doped w ith som e im purities (defects). For the tim ebeing we leave the theory describing the $w$ ire and also the nature of the im purities unspeci ed.
$H$ ere the defect operator $Z$ enters in-betw een the two local currents $J$ w ithin the tem perature $T$ and $m$ ass $m$ dependent correlation function. The $M$ atsubara frequency is denoted by!.

T he other possibility of determ ining the conductance which we want to study, is a generalization of the LandauerButtinger transport theory picture. W ithin this fram ew ork a proposal for the conductance through a quantum w ire w ith a defect (im purity) has been

which we only m odify to accom m odate parity breaking. This m eans we allow the trans$m$ ission am plitudes for a particle of type $i w$ ith charge $q_{i}$ passing $w$ ith rapidity through a defect of type from the left $T_{i}()$ and right $T_{i}()$ to be di erent. The density distribution function $\underset{i}{r}(; T ; i)$ depends on the tem perature $T$, and the potential at the left $\frac{l}{i}$ and right $\underset{i}{r}$ constriction of the wire.
 the transm ission am plitudes $T_{i}$, the current-current correlation functions $h:: i_{T, m}$ and the density distributions $i$. W e obtain all of them non-perturbatively, the $T$ 's by m eans of
 expansion and the 's from a therm odynam ic Bethe (TBA) ansatz [1]

## 2. Im purity system s

### 2.1 C onstraints from the generalized $Y$ ang $-B$ axter equations

Let $m$ e start $w$ ith the evaluation of the transm ission am plitudes, since they $w$ illbe required in (1]: m odels is that the n -particle scattering m atrix factorises into tw o -particle S -m atrioes, which can be determ ined by som e constraining equations such as the $Y$ ang $B$ axter $[1]=1]$ and boot-

 pure boundary, i.e. non-triviale ects on the constrictions, or purely transm itting defects will be rather uninteresting and we would like to consider the case when $R$ and $T$ are sim ultaneously non-vanishing. Unfortunately, it will tum out that for that situation the Yang-B axter equations are so constraining that not $m$ any integrable theories will be left to consider. Thus this section serves essentially to $m$ otivate the study of the free Ferm ion, which after all is very close to a realistic system of electrons propagating in quantum wires.

W e labelnow particle types by Latin and degrees of freedom of the im purity by $G$ reek letters, the bulk scattering $m$ atrix by $S$, and the left/right re ection and transm ission am plitu des of the defect by $R=R^{\curvearrowleft}$ and $T=T$, respectively. $T$ hen the transm ission and re ection am plitudes are constrained by the \unitarity" relations

$$
\begin{align*}
& R_{i}^{j}() R_{j}^{k}(\quad)+T_{i}^{j}() T_{j}^{k}(\quad)=\underset{i}{k} ;  \tag{2.1}\\
& R_{i}^{j}() T_{j}^{k}(\quad)+T_{i}^{j}() R_{j}^{k}(\quad)=0 ; \tag{22}
\end{align*}
$$

and the crossing-hem ticicity relations

$$
\begin{array}{ll}
R_{\mid}()=R_{\mid}( & )=S_{j \mid}(2) R_{j}(i \quad) ; \\
T_{\mid}()=T_{\mid}(\quad)=T_{j}(i \quad): \tag{2.4}
\end{array}
$$

The equations $(\underline{2}-\overline{1})$ Ind $(\underline{2} \overline{2})$ 2lso hold after perform ing a parity transform ation, that is for $R \$ R$ and $T \$ T$.

D epending now on the choice of the intial asym ptotic condition one can derive the follow ing two non-equivalent sets of generalized Yang-B axter equations by exploiting the


$$
\begin{align*}
& \left.S(12)\left[T()_{2}\right) T(1)\right]=\left[T\left({ }_{1}\right) \quad T(2)\right] S(12) \text {; } \tag{2.6}
\end{align*}
$$

and

$$
\begin{align*}
& \text { R (1) } R(2)=R(1) R(2) ;  \tag{2.8}\\
& {\left[\begin{array}{lll}
{[ } & (2) & I] S \\
(12)
\end{array} \mathbb{R}^{2}\left({ }_{1}\right) \quad \operatorname{I}\right] S(12)=T(2) \quad R(1) ;} \tag{2.9}
\end{align*}
$$

W e used here the convention (A $B)_{i j}^{k l}=A_{i}^{k} B{ }_{j}^{1}$ for the tensor product and abbreviated the rapidity sum $\hat{1}_{12}=1+\quad$ and di erence ${ }_{12}=1 \quad 2$. O nce again the sam e equations also hold for $R \$ R$ and $T$ \$ $T$.

A part from som e discrepancies in the indices the equations (2, $2=-(\underline{1})$ $m$ ore sim pli ed, in the sense that there w ere no degrees of freedom in the defect and parity invariance is assum ed, set ofequations considered previously in [24] ]. For diagonalscattering止 w as argued in $[\underline{[2} \overline{4} \overline{1}]$ that one can only have re ection and transm ission sim ultaneously w hen $S=1$. In $\left.{ }_{[1-1}^{[1]}\right]$ a $m$ ore general set up which includes all degrees of freedom was studied. A second set of equations $(\underset{2}{2},(1)-(\overline{1})$ was shown that in the absence of degrees of freedom in the defect no theory which has a non-diagonal bulk scattering $m$ atrix adm its sim ultaneous re ection and transm ission. $T$ his result even holds for the com pletely general case inchuding degrees of freedom in the defect upon a $m$ ild assum ption on the com $m$ utativity of $R$ and $T$ in these variables. It was further show $n$ that besides $S=1$ also the Federbush model [ $\overline{2}-\overline{4}]$ and the generalized coupled Federbush models $\left[\frac{1}{6}\right]$ allow for $R \in 0$ and $T \in 0$.

## 2 .2 M ultiple im purity system s

T hem ost interest situation in im purity system sarises w hen instead of a single one considers multiple defects, since that leads to the occurrence of resonance phenom ena and when the num ber of defects tends to in nity even to band structures. A ssum ing that the distance betw een the defects is sm all in com parison to the length of the w ire one can easily construct the transm ission and re ection am plitudes of them ultiple defect system from the know ledge of the corresponding quantities in the single defect system. For instance for two defects one obtains

$$
\begin{array}{ll}
T_{i}()=\frac{T_{i}() T_{i}()}{1 R_{i}() R_{i}()} ; & R_{i}()=R_{i}()+\frac{R_{i}() T_{i}() T_{i}()}{1 R_{i}() R_{i}()} ; \\
T_{i}()=\frac{T_{i}() T_{i}()}{1 R_{i}() R_{i}()} ; & R_{i}()=R_{i}()+\frac{R_{i}() T_{i}() T_{i}()}{1 R_{i}() R_{i}()}: \tag{2.13}
\end{array}
$$

$T$ hese expressions allow for a $_{P}$ direct intuitive understanding, for instance we note that the term $\left[1 \quad R_{i}() R_{i}()\right]^{1}={ }_{n=1}^{1}\left(R_{i}() R_{i}()\right)^{n}$ simply results from the in nite number of re ections which we have in foetw een the two defects. This is of course well known from Fabry P erot type deviges of classical and quantum optics. For the case $T=T ; R=R$ the expressions $(2.12)$ and $[2.13)$ coincide $w$ th the form ulae proposed in $[\underline{1} \underline{6}] . W$ hen absorbing the space dependent phase factor into the defect $m$ atrices, the explicit exam ple presented in $\left[\begin{array}{ll}{[\overline{4}} \\ \hline\end{array}\right]$ for the free $F e r m$ ion perturbed $w$ th the energy operator agree alm ost for $T=T ; R=R$ $w$ ith the general form ulae $[2 \overline{12})$. They disagree in the sense that the equally of $R_{i}()$ and $R_{i}()$ does not hold for generic ; as stated in [24] ${ }_{L}^{\prime-}$.

It is now straightforward to generalize the expressions for an arbitrary number of defects, say $n$, in a recursive $m$ anner

$$
\begin{equation*}
\mathrm{T}_{\mathrm{i}}^{\sim}()=\frac{\mathrm{T}_{\mathrm{i}}{ }^{1::: \mathrm{k}^{\mathrm{k}}}() \mathrm{T}_{\mathrm{i}}{ }^{\mathrm{k+1} 1::: \mathrm{n}^{n}}()}{1 \mathrm{R}_{\mathrm{i}}{ }^{1:::{ }_{k}}() \mathrm{R}_{\mathrm{i}}{ }^{\mathrm{k}+1:::{ }^{n}}()} ; \quad 1<\mathrm{k}<\mathrm{n} ; \tag{2.14}
\end{equation*}
$$

$$
\begin{equation*}
R_{i}()=R_{i}{ }^{1::: k_{k}}()+\frac{R_{i}{ }^{k+1}::: n_{n}() T_{i}{ }^{1::: k_{k}}() T_{i}^{1::: k^{k}}()}{1 R_{i}^{1::: k_{k}}() R_{i}{ }^{k+1::: n_{n}}()} ; \quad 1<k<n: \tag{2.15}
\end{equation*}
$$

$W$ e encoded here the defect degrees of freedom into the vector $\sim=f \quad 1$; $n g$; Sim ilar expressions also hold for $T_{i}^{\sim}()=T_{i}^{1::: n}()$ and $R_{i}^{\sim}()=R_{i}^{1::: n}()$.

A ltematively, we can de ne, in analogy to standard quantum $m$ echanicalm ethods (see e.g. [1] $\left.\left.\underline{i}_{1}^{1}\right]\right)$, a transm ission $m$ atrix which takes the particle $i$ from one side of the defect of type to the other

$$
M^{i}()=\quad \begin{gather*}
T_{i}()^{1}  \tag{2.16}\\
R_{i}() T_{i}()^{1}
\end{gather*} \mathrm{R}_{\mathrm{i}}() \mathrm{T}_{\mathrm{i}}()^{1} \mathrm{~T}_{\mathrm{i}}()^{1},
$$

Then altematively to the recunsive way $(2.14)$ and $(2,15)$, we can also com pute the $m$ ultidefect transm ission and re ection am plitudes as
$T$ his form ulation has the virtue that it is $m$ ore suitable for num erical com putations, since it just involves $m$ atrix $m$ ultiplications rather than recurrence operations. In addition it allow s for an elegant analytical com putation of the band structures for $n$ ! 1 , which I $w$ ill how ever not com $m$ ent upon further in this talk.

### 2.3 C onstraints from potential scattering theory

A s we argued in section $2.1 .$, in order to obtain a non-trivial conductance we are lead to consider free theories, possibly w ith som e exotic statistics. T rying to be as close as possible to som e realistic situation, i.e. electrons, we consider rst the free Ferm ion, which with a

 form of the energy operator and in $\left[\bar{p}_{\underline{9}}^{1}\right]$ also a perturbation in form of a single Ferm ion has been considered. In [1] [1] we treated a much w ider class of possible defects.

Let us consider the Lagrangian density for a com plex free Ferm ion $w$ ith 'defects ${ }^{1}$

$$
\begin{equation*}
L=(i @ m)+X_{n=1}^{X^{\prime}} D^{n}\left(; ; @_{t} ; @_{t}\right)\left(x \quad x_{n}\right): \tag{2.18}
\end{equation*}
$$

The defect is described here by the functions $D{ }^{n}\left(; ; @_{t} ; @_{t}\right)$; which we assum e to be linear in the Ferm i elds, and their time derivatives. W e can now proceed in

$$
\begin{aligned}
& { }^{1} \mathrm{~W} \text { e use the conventions: }
\end{aligned}
$$

W e adopt relativistic units $1=c=\sim=m \quad e^{2} 137$ as $m$ ostly used in the particle physics context rather than atom ic units $1=e=\sim=m \quad c=137 \mathrm{~m}$ ore natural in atom ic physics.
 and construct the am plitudes by adequate $m$ atching conditions on the eld. W e consider
rst a single defect at the origin which su ces, since multiple defect am plitudes can be constructed from the single defect ones, according to the argum ents of the previous section. W e decom pose the elds of the bulk theory as $(x)=(x)+(x)+(x) \quad(x)$, w ith
$(x)$ being the $H$ eavyside unit step function, and substitute this ansatz into the equations ofm otion. A s a m atching condition we read o the factors of the delta function and hence obtain the constraints

$$
\begin{equation*}
i^{1}(+(x) \quad(x)) j_{k=0}=\frac{@ D}{@(x)} \quad \frac{@}{@ t} \frac{@ D}{@\left(@_{t}(x)\right)} \quad x=0 \tag{2.19}
\end{equation*}
$$

W e then use for the left ( ) and right (+ ) parts of the well-known Fourier decom position of the free eld

$$
\begin{equation*}
\underset{j}{f}(x)={ }^{Z} \frac{d}{4} a_{j}() u_{j}() e^{i p_{j} x_{+}} a_{\mid}^{y}() v_{j}() e^{i p_{j} x} ; \tag{220}
\end{equation*}
$$

w ith the W eylspinors

$$
\begin{equation*}
u_{j}()=\quad i^{5} v_{j}()=\frac{r}{\frac{m_{j}}{2}} \quad e^{=2}=2! \tag{221}
\end{equation*}
$$

and substitute them into the constraint $(2,19)$. Treating the equations obtained in this $m$ anner com ponentw ise, stripping o the integrals, one can bring them thereafter into the form

$$
\begin{equation*}
a_{j ;}()=R_{j}() a_{j ;}(\quad)+T_{j}() a_{j ;+}() ; \tag{2,22}
\end{equation*}
$$

which de nes the re ection and transm ission amplitudes in an obvious manner. W hen parity invariance is broken, the corresponding am plitudes from the right to the left do not have to be identical and we also have

$$
\begin{equation*}
\mathrm{a}_{j ;+}(\quad)=\mathrm{T}_{j}() \mathrm{a}_{j ;}(\quad)+\mathrm{R}_{\mathrm{j}}() \mathrm{a}_{j ;+}(): \tag{223}
\end{equation*}
$$

The creation and annihilation operators $a_{i}^{y}()$ and $a_{i}()$ satisfy the usual ferm ionic anticommutation relations $f a_{i}\left({ }_{1}\right) ; a_{j}(2) g=0$, $f a_{i}\left({ }_{1}\right) ; a_{j}^{y}(2) g=2 \quad i j(12)$. In this way one $m$ ay construct the $R$ 's and $T$ 's for any concrete defect $w$ hid is of the generic form as described in (2, (2). A fter the construction one $m$ ay convince oneself that the expressions found this way indeed satisfy the consistency equations like unitarity $(\overline{2}-1), ~(\underline{1}-2)$ and
 construction, since they are not restrictive enough by them selves to determ ine the R 's and T's. W e consider now som e concrete exam ples:
2.3.1 Im purities of Luttinger liquid type D (; ) = ( $\left.g_{1}+g_{2}{ }^{0}\right)$ Luttinger liquids $\left[\underline{3} \mathbf{0} \mathbf{O}_{1}^{\prime}\right]$ are of great interest in condensed $m$ atter physics, which is one of the $m$ otivations for our concrete choige of the defect $D(;)=\left(g_{1}+g_{2}{ }^{0}\right)$. W hen taking the conform allim it of the defect one obtains an im purity which played a role in this
context, see e.g. [ $\overline{3} \overline{1} \overline{1} \overline{1}]$, after elim inating the bosonic num ber counting operator. In the way outlined above, we com pute the related transm ission and re ection am plitudes

$$
\begin{align*}
& R_{j}\left(; g_{1} ; g_{2} ; \quad y\right)=R_{j}\left(; g_{1} ; g_{2} ; y\right)=\frac{4 i\left(g_{2}+g_{1} \cosh \right) e^{2 i y m \sinh }}{\left(4+g_{1}^{2} g_{2}^{2}\right) \sinh 4 i\left(q+g_{2} \cosh \right)} ; \tag{2,24}
\end{align*}
$$

$$
\begin{align*}
& \left.T_{j}\left(; g_{1} ; g_{2}\right)=T_{j}\left(; g_{1} ; g_{2}\right)=\frac{\left(4+g_{2}^{2}\right.}{\left(4+g_{1}^{2}\right) \sinh } \quad \underline{q}^{2}\right) \sinh \quad 4 i\left(q+g_{2} \cosh \right) \quad ;  \tag{2,26}\\
& \left.\mathrm{T}_{\mid}\left(; g_{1} ; g_{2}\right)=\mathrm{T}_{\mid}\left(; g_{1} ; g_{2}\right)=\frac{\left(4+g_{2}^{2}\right.}{} \underline{q}^{2}\right) \sinh \quad\left(4+g_{1}^{2} \quad \underline{q}^{2}\right) \sinh \quad 4 i(\underline{q} \quad \underline{0} \cosh ):
\end{align*}
$$

In the $\lim$ it $\lim _{g_{2}}!0 \mathrm{D}(;)=g_{1}$, we recover the related results for the $T=T^{\prime} \mathrm{s}$ and $R=R^{\prime}$ 's for the energy defect operator. For this type of defect we present $\ddagger f$ and $\mathcal{f} f$ in gure 1 w ith varying param eters in order to illustrate som e of the characteristics of these functions.


Figure 1: (a) Single defect with varying coupling constant. 们 3 and $R \neq$ correspond to curves starting at 0 and 1 of the sam e line type, respectively. (b) D ouble defect $w$ ith varying distance y . (c) D ouble defect with varying e ective coupling constant $B=\arcsin \left(4 g_{1}=\left(4+g_{1}^{2}\right)\right)$. (d) D ouble defect dotted line, eight defects solid line.
$P$ art (a) of gure 1 con $m$ s the untarity relation ( $\overline{2} \cdot \underline{1})$. 1 Part (b) and (c) show the typical resonances of a double defect, which becom e stretched out and pronounced w ith respect to the energy w hen the distance becom es sm aller and the coupling constant increases, respectively. Part (d) exhibits a general feature, that is when the num ber of defects is increased, for xed distance betw een the outerm ost defects, the resonances becom em ore and $m$ ore dense in that region such that one $m$ ay speak of energy bands.

### 2.3.2 The defect $D\left(; ; @_{t} ; @_{t}\right)=i g=2\left(@_{t} @\right)$

$T$ his type of defect rem inds on the rst non-trivial charge occurring in the free Ferm ion $m$ odel. In this case we com pute by the sam e $m$ eans the related transm ission and re ection am plitudes to

$$
\begin{gather*}
R_{j}(; y)=R_{\mid}(; y)=R_{j}(; y)=R_{\mid}(; y)=\frac{4 i g \cosh e^{2 i y m \sinh }}{4 i g+\tanh \left(4+g^{2} \cosh ^{2}\right)} ;  \tag{2.28}\\
T_{j}()=T_{j}()=T_{\mid}()=T_{\mid}()=\frac{\left(4 g^{2} \cosh ^{2}\right) \tanh }{4 i g+\tanh \left(4+g^{2} \cosh ^{2}\right)}: \tag{229}
\end{gather*}
$$

In [11] we also com puted the $T=T^{\prime}$ ' and $R=R^{\prime}$ 's for other types of defects, such as $\mathrm{D}=\mathrm{g}^{1}, \mathrm{D}=\mathrm{g}{ }^{5}, \mathrm{D}=\mathrm{g}\left(\mathrm{D}^{1}{ }^{5}\right)::: A \mathrm{~s}$ an overall conclusion we observed that all possible types of parity breaking, that is $T \in T$; $R \in R$ or $T \in T ; R=R$, etc., do occur. W e also con $m$ a general principle one know $s$ well from quantum mechanics, nam ely that parity is preserved when the potential is real, that is in this case the defect satis es D = D.
2.4 Im purities coupled to laser elds

Let us now consider a m ore com plex situation in which a three dim ensional laser eld hits the quantum $w$ ire polarized in such a way that it has a vector eld com ponent along the $w$ ire. Since the work of $W$ eyl $[\overline{3} \overline{2} \overline{1}]$, one know $s$ that $m$ atter $m$ ay be coupled to light by $m$ eans of a local gauge transform ation, which re ects itself in the usualm in im al coupling prescription, i.e. @ ! @ ieA, with A being the vector gauge potential. The free Ferm ions in the w ire are then described by the Lagrangian density

$$
\begin{equation*}
L_{\mathrm{A}}=(i @ m+e A): \tag{2.30}
\end{equation*}
$$

W hen the laser eld is sw itched on, we can solve the equation of $m$ otion associated to (2-30)

$$
\begin{equation*}
\text { (i } @ m+e A)=0 \tag{2.31}
\end{equation*}
$$

by a G ordon-Volkov type solution [B]_ㄹ]

$$
\begin{equation*}
{ }_{j}^{A}(x ; t)=\exp \text { ie } \mathrm{X}^{\mathrm{Z}} \mathrm{ds} A_{1}(\mathrm{~s} ; \mathrm{t}) \quad{ }_{j}^{f}(x ; t)=\exp \text { ie } \mathrm{XdA}_{0}(x ; s) \quad{ }_{j}^{\mathrm{f}}(\mathrm{x} ; \mathrm{t}): \tag{2.32}
\end{equation*}
$$

U sing now a linearly polarized laser eld along the direction of the w ire, the vector potential can typically be taken in the dipole approxim ation to be a supenposition ofm onochrom atic
light w ith frequency ! , i.e.
$A(t):=A_{1}(t)=\frac{1}{x}_{0}^{Z} \operatorname{dsA}_{0}(s)=\frac{1^{Z}}{2} 0_{0}^{t} \operatorname{dsE}(s)=\frac{E}{0}^{Z}{ }_{0}^{t} d s f(s) \cos (!s)$
$w$ ith $f(t)$ being an arbitrary enveloping function equalto zero for $t<0$ and $t>$, such that denotes the pulse length. In the follow ing we w ill alw ays take $f(t)=(t)(t)$, with
 $x A(t)$, follow s from the fact that we have to solve ( 2

I want to com m ent on the validily of the dipole approxim ation in this context. It consists usually in neglecting the spatial dependence of the laser eld, which is justi ed when x ! < $\mathrm{c}=1$, where x is a representative scale of the problem considered. In the context of atom ic physics this is typically the Bohr radius. In the problem investigated here, this approxim ation has to hold over the fullspatial range in which the Ferm ion follow s the electric eld. W e can estim ate this classically, in which case the $m$ axim al am plitude is $\mathrm{eE}{ }_{0}=!^{2}$ and therefore the follow ing constraint has to hold

$$
\begin{equation*}
{\frac{e E_{0}}{!}}^{2}=4 \mathrm{U}_{\mathrm{p}}<1 \tag{2.34}
\end{equation*}
$$

for the dipole approxim ation to be valid. D ue to the fact that $x$ is a function of ! , we have now a lower bound on the frequency rather than an upper one as is $m$ ore com $m$ on in the context of atom ic physics. W e have also introduced here the ponderom otive energy $U_{p}$ for $m$ onochrom atic light, that is the average kinetic energy transferred from the laser eld to the electron in the w ire.
$T$ he solutions to the equations ofm otion of the free system and the one which includes the laser eld are then related by a factor sim ilar to the gauge transform ation from the length to the velocity gauge

$$
\begin{equation*}
\underset{j}{A}(x ; t)=\exp [i x e A(t)]{ }_{j}^{f}(x): \tag{2.35}
\end{equation*}
$$

In an analogous fashion one $m$ ay use the sam e $m$ inim al coupling procedure also to couple in addition the laser eld to the defect. O ne has to invoke the equation ofm otion in order to carry this out. For convenience we assum e now that the defect is linear in the elds and . The Lagrangian density for a com plex free Ferm ion with 'defects D ( ; ;A ) of type at the position $\mathrm{x}_{\mathrm{n}}$ sub jected to a laser eld then reads

$$
\begin{equation*}
L_{A D}=L_{A}+X_{n=1}^{X^{\prime}}{ }^{n}(; \quad ; A)\left(x \quad x_{n}\right): \tag{2.36}
\end{equation*}
$$

C onsidering for simplicity rst the case of a single defect situated at $x=0$, the solution to the equation of $m$ otion resulting from $[2 \overline{2} \bar{\sigma})$ is taken to be of the form ${ }_{j}^{A}(x ; t)=$
( $x$ ) $\underset{j ;+}{A}(x ; t)+(x) \underset{j}{A}(x ; t)$, which $m$ eans as before we distinguish here by notation the solutions $\left[2=35_{1}^{\prime}\right)$ on the left and right of the defect, $\underset{j}{A} ;(x ; t)$ and $\underset{j ;+}{A}(x ; t)$, respectively. $P$ roceeding as before, the $m$ atching condition reads now

$$
\begin{equation*}
i^{1}(\underset{j ;+}{A}(x ; t) \quad \underset{j}{A} ;(x ; t)) j_{k}=0=\frac{@ D_{A D}(; ; A)}{@ \underset{j}{A}(x ; t)} \underset{x=0}{ }: \tag{2.37}
\end{equation*}
$$

It is clear, that in this case the transm ission and re ection am plitudes w ill in addition to and $g$ also depend on the characteristic param eters of the laser eld

$$
\begin{equation*}
\mathrm{T}\left(; g_{;} \mathrm{E}_{0} ;!; \mathrm{t}\right) \quad \text { and } \quad \mathrm{R}\left(; \mathrm{g}_{\boldsymbol{j}} \mathrm{E}_{0} ;!; \mathrm{t}\right): \tag{2.38}
\end{equation*}
$$

$W$ ith regard to the $m$ ain them $e$ of this talk, it is clear that the laser eld can be used to control the conductance. For instance defects which have transm ission am plitudes of the form as the solid line in gure 1 (c), can be used as optically controllable sw itching devices. I want to deviate now slightly from the $m$ ain line of argum ent and report brie $y$ on an interesting phenom enon one can predict $w$ ith solutions of the type ( 2

### 2.5 H arm on ic generation

Let me rst brie $y$ explain what harm onics are. The rst experim ental evidence can be traced back to the early sixties $\left[\underline{3} \overline{4} \overline{4}_{1}^{\prime}\right]$. Franken et al found that when hitting a crystalline quartz $w$ ith a weak ultraviolet laser beam of frequency!, it em its a frequency which is 2 !. G eneralizing this phenom enon to higher multiples, one says now adays that high harm onics generation is the non-linear response of a m edium (a crystal, an atom, a gas, ...) to a laser eld. H arm onic generation is im portant, since it allow s to convert infrared input radiation of frequency ! into light in the extrem e ultraviolet regim e whose frequencies are multiples of! (even up to order 1000, see e.g. spectrum is presented in gure 2.

In gases, com posed of atom $s$ or sm allm olecules, this phenom enon is well-understood and, to som e extent, even controllable in the sense that the frequency of the highest harm onic, the so-called \cut-o ", visible in $9-$ ure 2, can be tuned as well as the intensities of particular groups of har$m$ onics. In $m$ ore com plex system $s$, how ever, for instance solids, or larger m olecules, high-harm onic generation is still an open problem. This is due to the fact that, until a few years ago, such system s w ere expected not to survive the strong laser elds one needs to produce such e ects. H ow -


Figure 2: H arm onic spectrum for $N$ eon for a $T$ isa laser w th $=795 \mathrm{~nm}$. M easured at the M ax Bom Institut Berlin [ B - G$]$ ever, now adays, w ith the advent of ultrashort pulses, there exist solid-state $m$ aterials $w$ hose dam age threshold is beyond the required intensities of $10^{14} \mathrm{~W}=\mathrm{cm}^{2}\left[\overline{3} \bar{Z}_{1}\right]$. A s a direct consequence, there is an increasing interest in such $m$ aterials as potential sources for highharm onics. In fact, several groups are currently investigating this phenom enon in system s such as thin crystals $[\underline{3} \bar{z}, 1,1]$

W e w ill therefore try to answer here the question, whether it is possible to generate harm onics from solid state deviges and as a prototype of such a system we study a quantum w ire coupled to the laser eld in the way described in section 2.4.

In order to answ er that question, we rst have to study the spectrum of frequencies which is ltered out by the defect while the laser pulse is non-zero. T he Fourier transform $s$ of the re ection and transm ission probabilities provide exactly this inform ation

$$
\begin{align*}
& R\left(; \quad ; E_{0} ;!\right)=\frac{1}{0} \operatorname{dt-R}\left(; E_{0} ;!; t\right) \jmath^{2} \cos (t): \tag{2.39}
\end{align*}
$$

W hen parity is preserved for the re ection and transm ission am plitudes, that is for real defects w ith $D=D$, we have 俭 $f+R f=1$, and it su ces to consider $T$ in the follow ing.

### 2.5.1 Type I defects

$M$ any features can be understood analytically. Taking the laser eld in form ofm onochro$m$ atic light in the dipole approxim ation $(2,33)$, we $m$ ay naturally assum $e$ that the trans $m$ ission probability for som e particular defects can be expanded as

$$
\begin{equation*}
\mathfrak{T}_{\mathrm{I}}\left(; \mathrm{U}_{\mathrm{p}} ;!; \mathrm{t}\right) \mathcal{J}^{2}=\mathrm{X}_{\mathrm{k}=0}^{\mathrm{I}} \mathrm{t}_{2 \mathrm{k}}()\left(4 \mathrm{U}_{\mathrm{p}}\right)^{\mathrm{k}} \sin ^{2 \mathrm{k}}(!\mathrm{t}): \tag{2.41}
\end{equation*}
$$

W e shall refer to defects which adm it such an expansion as \type I defects". A ssum ing that the coe cients $t_{2 k}()$ becom e at $m$ ost 1 , we have to restrict our attention to the regim e $4 \mathrm{U}_{\mathrm{p}}<1$ in order for this expansion to be meaningful for all $t$. $N$ ote that this is no further lim itation, since it is precisely the sam e constraint as already encountered for the validity
 hold for various explicit defects considered below. B ased on this equation, we com pute for such type of defect

It is clear from this expression that type I defects w ill preferably let even multiples of the basic frequency! pass, whose am plitudes will depend on the coe cients $t_{2 k}$ ( ) . W hen we choose the pulse length to be integer cycles, i.e. $=2 \mathrm{n}=$ ! for n 2 Z , the expression in [2.42) reduces even further. $T$ he values at even $m$ ultiples of the basic frequency are sim ply

$$
\begin{equation*}
T_{\mathrm{I}}\left(2 \mathrm{n}!; ; \mathrm{U}_{\mathrm{p}}\right)=(1)^{\mathrm{X}^{\mathrm{A}}} \mathrm{t}_{2 \mathrm{k}}()\left(\mathrm{U}_{\mathrm{p}}\right)^{\mathrm{k}} \mathrm{k}_{\mathrm{k}}^{2 \mathrm{k}} \quad \mathrm{n} \text {; } \tag{2.43}
\end{equation*}
$$

which becom es independent of the pulse length . N otioe also that the dependence on $E_{0}$ and ! occurs in the com bination of the ponderom otive energy $U_{p}$. Further statem ents require the precise form of the coe cients $t_{2 k}()$ and can only be $m$ ade $w$ ith regard to $a$ $m$ ore concrete form of the defect.

### 2.5.2 Type II defects

C learly, not all defects are of the form (2. $4 . \overline{1}$ ) and we have to consider also expansions of the type

$$
\begin{equation*}
\mathbb{F}_{\text {II }}\left(; E_{0}=e ;!; t\right) \jmath^{2}={ }_{k ; p=0}^{X^{I}} t_{k}^{p}() \frac{E_{0}^{2 k+p}}{!^{2 k}} \cos ^{p}(!t) \sin ^{2 k}(!t): \tag{2.44}
\end{equation*}
$$

W e shall refer to defects which adm it such an expansion as \type II defects". In this case we obtain

W e observe from this expression that type II defects $w$ ill lter out all multiples of ! . For the pulse being once again of integer cycle length, this reduces to
and

$$
\begin{align*}
& T_{\text {II }}\left((2 n \quad 1)!; ; E_{0}=e\right)=X_{k ; p=0}^{X^{2}} X^{p}(1)^{1+n+1} \frac{t_{2 k}^{2 p+1}()}{2^{2 l} 2 p+1}\left(U_{p}\right)^{k+p} \\
& \mathrm{p}^{\mathrm{l}} \frac{(2 \mathrm{k}+2 \mathrm{l})!(2 \mathrm{n} \quad 1) \mathrm{E}_{0}^{2 \mathrm{p}+1}}{(1+\mathrm{k} \quad \mathrm{n}+1)!(1+\mathrm{n}+\mathrm{k})!} ; \tag{2.47}
\end{align*}
$$

which are again independent of. W e observe that in this case we can not com bine the $E_{0}$ and ! into $a U_{p}$.

### 2.5.3 O ne particle approxim ation

In spite of the fact that we are dealing w ith a quantum eld theory, it is know $n$ that a one particle approxim ation to the D irac equation is very useful and physically sensible when the extemal forces vary only slow ly on a scale of a few $C$ om pton $w$ avelengths, see e.g. [4]3'] W e m ay therefore de ne the spinor wavefunctions

W ith the help of these functions we obtain then for the defect system

$$
\begin{align*}
& \underset{i ; u ;}{A}(x ; t):=\underset{i}{A}(x ; t) \frac{a_{i}^{Y}()^{E}}{\frac{E}{2^{2} p_{i}^{0}}}=(x)\left[i ; u ;(x ; t)+\underset{i ; u ;}{ }(x ; t) R_{i}()\right] \\
& +(x) T_{i}() \quad i ; u ;(x ; t)+i ; u ; \quad(x ; t) R_{i}^{r}() \tag{2.50}
\end{align*}
$$

and the sam e function w th u ! v. Since this expression resembles a free wave, it can not be norm alized properly and we have to localize the wave in form of a wave packet by m ultiplying $w$ ith an additional function, $g(p ; t)$ in $(2-20)$ and its countenpart $g(x ; t)$ in $[2-50,1)$, typically a G au ian. Then for the function $\underset{i ; u}{A}(x ; t)=g(x ; t) \underset{i}{A} \underset{i}{A} ;(x ; t)$, we can achieve that k k=1.

### 2.5.4 H arm onic spectra

W e are now in the position to determ ine the em ission spectrum for which we need to com pute the absolute value of the Fourier transform of the dipole $m$ om ent

$$
\begin{align*}
& \text { Z D E } \tag{2.51}
\end{align*}
$$

W e localize now the w ave packet in a region much sm aller than the classical estim ate for the $m$ axim alam plitude the electron willacquire when follow ing the laser eld. W e achieve this w ith a G au ian $g(x ; t)=\exp \left(x^{2}=\right)$, where eE $0=!^{2}$.
2.5.5 A n exam ple: Im purity of energy operator type

A smentioned this type of defect, i.e. D (; ) = $\mathrm{g} \quad(\mathrm{x})$ can be obtained in a lim it from the defect discussed in section 2.3.1. C oupling the vector potentialm inim ally to it yields

$$
\begin{equation*}
D_{A D}(; ; A)=g(1+e=m \quad A) ; \tag{2.52}
\end{equation*}
$$

by invoking the equation ofm otion. W e can now determ ine the re ection and transm ission am plitudes as outlined above

$$
\begin{align*}
& R_{i}(; q ; A=e ; y)=R_{i}(; q ; \quad A=e ; \quad y)=R_{i}(; q ; A=e ; \quad y)=R_{i}(\eta ; \quad A=e ; y)= \tag{2.53}
\end{align*}
$$

$W$ e denoted the di erentiation $w$ ith respect to tim e by a dot. T he transm ission am plitudes tum out to be

$$
\begin{align*}
T_{i}(; g ; A=e ; y)= & T_{i}(; g ; \quad A=e ; \quad y)=T\left(; g ; \quad A_{i}=e ; y\right)=T_{i}(; g ; A=e ; \quad y)= \\
& \frac{i 1 \quad Y^{2} A^{2}+\left(A \quad \frac{2 i}{g}\right)^{2} \sinh }{\left.\frac{4}{9}[1 \quad y A-\cosh ] \quad i \frac{4}{g^{2}}+1+A^{2} \quad y^{2} A^{2}\right] \sinh }:
\end{align*}
$$

Locating the defect at $y=0$, the derivative of $A$ does not appear anym ore explicitly in [2.53) and $(2.54)$, such that it is clear that this defect is oftype I and adm its an expansion of
the form $(2.4 \overline{1})$ ) $W$ ith the explicit expressions $(2-53)$ and $(2.54)$ at hand, we can determ ine all the coe cients $t_{2 k}()$ in $(2, A \overline{1})$ ) analytically. For this punpose let us rst bring the transm ission am plitude into the $m$ ore sym $m$ etric form

$$
\begin{equation*}
\Vdash_{i}(; g ; A=e) \jmath^{2}=\frac{a_{0}(; g)+a_{2}(; g) A^{2}+a_{4}(; g) A^{4}}{a_{0}(; g)+a_{2}(; g) A^{2}+a_{4}(; g) A^{4}} ; \tag{2.55}
\end{equation*}
$$

w ith

$$
\begin{array}{ll}
a_{0}(; g)=16 g^{2}+\left(4+g^{2}\right)^{2} \sinh ^{2} ; & a_{0}(; g)=\left(g^{2} \quad 4\right)^{2} \sinh ^{2} ; \\
a_{2}(; g)=2 g^{2}\left(4+g^{2}\right) \sinh ^{2} ; & a_{4}(; g)=g^{4} \sinh ^{2}: \tag{2.57}
\end{array}
$$

W e can now expand $\boldsymbol{j}(; g ; A) J^{2}$ in powers of the eld $A(t)$ and identify the coe cients
 sion of the denom inator in $(2,55)$. The latter adm its the follow ing com pact form

$$
\begin{equation*}
\frac{1}{a_{0}(; g)+a_{2}(; g) A^{2}+a_{4}(; g) A^{4}}=X_{k=0}^{X^{1}} c_{2 k}(; g) A^{2 k} \tag{2.58}
\end{equation*}
$$

$w$ th $c_{0}(; g)=1=a_{0}(; g)$ and

$$
\begin{equation*}
\mathrm{c}_{2 \mathrm{k}}(; g)=\frac{\mathrm{c}_{2 \mathrm{k}}{ }_{2}(; g) \mathrm{a}_{2}(; g)+\mathrm{c}_{2 \mathrm{k}}{ }_{4}(; g) \mathrm{a}_{4}(; g)}{\mathrm{a}_{0}(; g)} ; \tag{2.59}
\end{equation*}
$$

for $k>0$. We understand here that all coe cients $\mathrm{C} 2 \mathrm{k} w$ th $\mathrm{k}<0$ are vanishing, such that from this formula all the coe cients $c_{2 k} m$ ay be com puted recursively. H ence, by com paring w th the series expansion (2,41), we nd the follow ing closed form ula for the coe cients $t_{2 k}(; g)$

$$
\begin{equation*}
t_{2 k}(; g)=\left[a_{0}(; g) \quad a_{0}(; g)\right]_{2 k}(; g) \quad k>0: \tag{2.60}
\end{equation*}
$$

T he rst coe cients then sim ply read

$$
\begin{align*}
& t_{0}(; g)=\frac{a_{0}(; g)}{a_{0}(; g)}=\mathfrak{J}\left(; E_{0}=0\right) \mathcal{J}^{2} ;  \tag{2.61}\\
& t_{2}(; g)=\frac{a_{2}(; g)}{a_{0}(; g)}\left[1 \quad t_{0}(; g)\right]=\frac{8 g^{4}\left(4+g^{2}\right) \sinh ^{2} 2}{\left(16 g^{2}+\left(4+g^{2}\right)^{2} \sinh ^{2}\right)^{2}} ;  \tag{2.62}\\
& t_{4}(; g)=\frac{a_{4}(; g)}{a_{2}(; g)} \frac{a_{2}(; g)}{a_{0}(; g)} t_{2}(; g) ; \tag{2.63}
\end{align*}
$$

and so on. It is now clear how to obtain also the higher term s analytically, but since they are rather cum bersom e we do not report them here.
 principle to any desired order. For som e concrete values of the laser and defect param eters the results of our evaluations are depicted in gure 3.

The $m$ ain observation from part (a) is that the defect acts as a lter selecting higher harm onics of even order of the laser frequency. Furthem ore, from the zoom of the peak


Figure 3: Fourier transform of the transm ission probability for a single (a) and double (b) defect $w$ th $E_{0}=2: 0, g=3: 5,=1: 2,!=0: 2$. H arm on ic em ission spectrum for a single (c) and double (d) defect $w$ ith $\mathrm{E}_{0}=2: 0, \mathrm{~g}=3: 5,=1: 2,!=0: 2,=6$.
regions, we see that there are satellite peaks appearing near the $m$ ain ham onics. They reduce their intensity when is increased, such that w ith longer pulse length the harm on ics becom em ore and $m$ ore pronounced. $W$ e also investigated that for di erent frequencies ! the general structure w ill not change. Increasing the eld am plitude $\mathrm{E}_{0}$, sim ply liffs up the whole plot without altering very much its overall structure. W e support these ndings in tw o altemative ways, eitherby com puting directly (2.39) num erically or, $m$ ore instructively, by evaluating the sum $s(2,42 \overline{2})$ and $(2,-43)$.

Part (b) show s the analysis for a double defect system with one defect situated at $\mathrm{x}=0$ and the other at $\mathrm{x}=\mathrm{y}$. The double defect amplitudes are com puted directly from $[2,12)$ and $(2,13)$ w th the expression for the single defect $(2,53)$ and ( $(2,54)$. Since now both $A$ and $A$ - appear explicitly in the form ulae for the R's and $T$ 's, it is clear that the expansion of the double defect can not be of type I, but it tums out to be of type II, i.e. of the form (2-4.4). H ence, we w ill now expect that besides the even also the odd multiples of! w ill be ltered out, which is indeed visible in part (b) for various distances. Here we have only plotted a continuous spectrum for $y=0: 5$, whereas for reasons of clarity, we only drew the enveloping function which connects the $m$ axim a of the harm onics for
the rem aining distances. W e observe that now not only odd multiples of the frequency em erge in addition to the ones in (a) as ham onics, but also that we obtain m uch higher harm onics and the cut-o is shifted further to the ultraviolet. Furtherm ore, we observe a regular pattem in the enveloping function, which appears to be independent of y. Sim ilar pattems were observed before in the literature, as for instance in the context of atom ic physics described by a K lein-G ordon form alism (see gure 2 in [й $\overline{4}$

C om ing now to the m ain point of our analysis we would like to see how this structure is re ected in the harm onic spectra. T he result of the evaluation of ( $2 \cdot 51$ gure 3 parts (c) and (d). W e observe a very sim ilar spectrum as we have already com puted for the Fourier transform of the transm ission am plitude, which is not entirely surprising w ith regard to the expression $(2,51)$. The cuto frequencies are essentially identical. From the com parison betw een $X$ and the enveloping function for $T$ we deduce, that the term involving the transm ission am plitude clearly dom inates the spectrum .

The im portant general deduction from these com putations is of course that harm onics of higher order do em erge in the em ission spectrum of im purity system s , such that

W e proposed in $\left[\begin{array}{l}\overline{1} 1]\end{array}\right]$ generalization of $(\overline{3} \overline{1})$ in the form of $[\overline{1}]$
 current-current correlation functions $h J(r) J(0) i_{T, m}$ or $h J(r) Z J(0) i_{T, m}$, respectively.

In the zero tem perature regim e two-point correlation functions can be com puted in
 expands the two-point function betw een two localoperators $O$ and $O^{0}$ in term $s$ of the series
$w h e r e$ we choose $x=(i r ; 0)$. The form factors are de ned as $m$ atrix elem ents of the local operator $O(x)$ located at the origin betw een a multiparticle in-state and the vacuum,

The expansion $[\overline{3} \mathbf{2} \mathbf{2})$ is sim ply obtained by inserting com plete states on the rh s. O ne m ay proceed sim ilarly by inserting one $m$ ore set of com plete states $w$ hen a defect is present and
obtains


$$
\begin{equation*}
Z_{n}\left(n_{n}\right)::: Z_{1}\left(r_{1}\right) \not Z_{1} Z_{1}\left(\sim_{1}\right)::: Z_{m}\left(\sim_{m}\right) F_{m}^{J j 1::: m}\left(\sim_{1}::: \sim_{m}\right) e^{r_{i=1}^{P_{i}} m_{i} \cosh i}: \tag{3.4}
\end{equation*}
$$

$T$ his $m$ eans there are three principle steps left in order to obtain the conductance from the expression in $(\overline{1}-1,1)$. (a) $T$ he computation of the form factors $[\overline{3} \overline{3})$ and the $m$ atrix elem ents involving the defect operator occurring in (3). (b) $T$ he integration in $r$ and (c) the lim it! ! 0. Step (a) can be perform ed in tw o altemative ways either by solving certain consistency equations for the form factors and defect $m$ atrix elem ents or by direct com putation. For the latter we require a representation for the particle creation operators Z ( ), the defect operator Z and the localoperator $O(r)$ which is the current in th is case.

### 3.1 T he m assless lim it

Rem arkably when carrying out the $m$ assless lim it of the above expressions, the steps (b) and (c) can be carried out generically. To perform such a lim it we proceed according to the $m$ assless lim it prescription as suggested originally in [ $\left[\underline{4} \overline{5}_{1}\right]$. It consists of carrying out the $\lim$ it $m$ ! 0 in the high energy regime. In order to do this one replaces in every rapidity dependent expression by ,where an additional auxiliary param eter has been introduced. Thereafter one takes the lim it ! $1, m!0$ while keeping the quantity $\mathrm{m}=m=2 \exp (\mathrm{)}$ nite. For instance, carrying out this prescription for the $m$ om entum yields $p=m \hat{e x p}(\quad)$, such that one $m$ ay view the $m$ odel as splitted into its two chiral sectors and one can speak naturally of left (L) and right ( $R$ ) m overs. For the form factors in [3]. $\overline{-1}$ ) the m assless lim it yields

$$
\begin{equation*}
\lim _{!} F_{n}^{0 j_{1}::: n_{n}}\left(1+1 ;::: ;_{n}+n\right)=F_{1}^{0 j_{1}::: n_{n}^{n}}\left(1 ;::: ;_{n}\right) ; \tag{3.5}
\end{equation*}
$$

$w_{i}$ th $_{i}=1$ and $_{i}=R$ for $i=+$ and $_{i}=L_{\text {for }}^{i}=\quad . N a m$ ely, in the $m$ assless lim it every $m$ assive $n$-particle form factor is $m$ apped into $2^{n} m$ assless form factors. $U$ sing these expressions, perform ing a $W$ idk rotation and introducing the variable $E=P_{i=1}^{n} m_{i} e^{i}$, we obtain from (3, $\mathbf{3}_{1}^{-1}$ )

W e note that for the $m$ assless prescription to work, the $m$ atrix elem ent involving the defect $Z$ can only depend on the rapidity di erences, which will indeed be the case as we see
 w rite the rh s. of ( $\overline{-1} .6$ ) as
$W$ e substitute now this correlation function into the $K$ ubo form ula, shift all rapidities as
 and carry out the integration in $d E{ }^{0}$

$$
\begin{align*}
& \mathbb{x}^{1} \tag{3.8}
\end{align*}
$$

W e state various observations: Since the $m$ atrix elem ent involving the defect only depends on the rapidity di erence, it is not a ected by the shifts. O perators $w$ ith Lorentz spin $s=1$ play a very special role in (3, In that case the r.h.s. of (3.8) becom es independent of the frequency ! and the lim it is carried out trivially. Furtherm ore, since the nal expression has to be independent of $\mathrm{m}_{\mathrm{n}}$, we deduce that the form factors have to be linearly dependent on $\mathrm{m} \mathrm{n}_{\mathrm{n}}$.

### 3.2 R ealization of the defect operator

A realization of $Z$ can be achieved very $m$ uch in analogy to a realization of localoperators, i.e. as exponentials of bilinears in Zam olodchikov\{Faddeev operators [îq]. For the case of a boundary a generic model independent realization for the boundary operator B was originally proposed in [2]d for the parity invariant case, i.e. $R=\pi$. This proposal was generalized to the defect operator in $[\overline{[ } \bar{\alpha} \bar{G}]$ w th the sam e restriction and for self-con jugated particles. H ere we extend this realization in order to incorporate the possibility of parity breaking as well as non self-con jugated particles. A non-trivial consistency check for the validity of our proposalw illbe ultim ately provided when exploiting it in the com putation of the conductance, obtained by entirely di erent $m$ eans as $w i l l$ be presented in part II. $T$ he realization we want to propose here is a direct generalization of the one presented in [2]-], nam ely

$$
\begin{equation*}
Z=: \exp \left[\frac{1}{4}_{1}^{Z_{1}} D \quad() d\right]: ; \tag{3.9}
\end{equation*}
$$

where : : denotes norm al ordering and the operator D () has the form

$$
\begin{align*}
& D \quad()=X^{X} \quad K_{i}() Z_{i}^{Y}() Z_{i}^{Y}(\quad)+K_{i}() Z_{i}(\quad) Z_{i}() \\
& \text { i i } \\
& +W_{i}() Z_{i}^{Y}() Z_{i}()+W_{i}() Z_{i}^{Y}(\quad) Z_{i}(\quad) ; \tag{3.10}
\end{align*}
$$

[^0]with $K_{i}()=R_{i}\left(\frac{i}{2} \quad\right), K_{i}()=R_{i}\left(\frac{i}{2} \quad\right), W_{i}():=T_{i}\left(\frac{i}{2} \quad\right)$ and $W_{i}():=$
 since in general we have contributions in the sum over i in (3.10) including both particles and anti-particles, as for the com plex free Ferm ion we shall treat below. Follow ing the


3.3 D efect m atrix elem ents
$H$ aving now a concrete generic realization of the defect [3]. ${ }^{-1}$ ), we can com pute the defect $m$ atrix elem ents. O ne way of doing this is to solve a set of consistency equations whidh relate the low er particle $m$ atrix elem ents to higher particle ones, sim ilar as in the standard
 a parity invariant defect and for a real free ferm ionic and bosonic theory. W e generalize this here and note rst that the operator ( $\left.\overline{3} \overline{-}, \mathbf{B}_{1}^{\prime}\right)$ becom es
\[

$$
\begin{equation*}
\lim _{R ; R!0 ; T ; T!1} Z=: \exp \left[\frac{1}{2} \int_{1}^{Z} d_{i}^{X} Z_{i}^{Y}() Z_{i}()\right]: ; \tag{3.11}
\end{equation*}
$$

\]

and the defect should act in th is case as the identity operator, which xes our norm alization to $h Z_{i}(1) Z \quad Z_{j}^{Y}(2) i=2 \quad(12)$ ij after having contracted according to $W$ idk's theorem . For two particles we nd,

$$
\begin{align*}
& h Z_{i}\left(1_{1}\right) Z_{i}(2) Z \quad i=\hat{K}_{i}(2)\left({ }_{12}\right) \text {; }  \tag{3.12}\\
& h Z Z_{i}^{Y}\left({ }_{1}\right) Z_{i}^{Y}(2) i=\hat{K}_{i}\left({ }_{1}\right) \quad\left({ }_{12}\right) \text {; }  \tag{3.13}\\
& h Z_{i}\left({ }_{1}\right) Z \quad Z_{j}^{Y}(2) i=\hat{W_{i}}(1)(12) i j: \tag{3.14}
\end{align*}
$$

For later convenience we have introduced the functions

$$
\begin{align*}
& \hat{K}_{i}()=K_{i}()+S_{\{i}(2) K_{i}(\quad)=K_{i}()+S_{i \ell}(2) K_{i}() ;  \tag{3.15}\\
& \hat{W}_{i}()=W_{i}()+W_{i}()=W_{i}()+W_{i}()=\hat{W}_{i}() ; \tag{3.16}
\end{align*}
$$

since the $K_{i}, K_{i}, W_{i}$ and $\tilde{W}_{i}$ amplitudes de ned before $w i l l$ repeatedly appear in the
 sim ply from

$$
\begin{equation*}
W_{i}()=W_{\{ }(\quad)=W_{\ell}(i \quad) ; K_{i}()=S_{i\{ }(2) K_{\ell}(\quad)=S_{i\{ }(2) K_{\{ }(i \quad) ; \tag{3.17}
\end{equation*}
$$

which are in tum consequences of the crossing-hem iticity properties $\left(\underline{2}-\mathbf{Z}_{1}\right)-\left(\underline{2} . \mathbf{n}^{2}\right)$. W ith these $m$ atrix elem ents we can construct the ones involving m ore particles recursively from

$$
\begin{align*}
& \text { Xn 竍 } 1 \tag{3.18}
\end{align*}
$$

$$
\begin{aligned}
& \mathrm{l}=2 \quad \mathrm{p}=1
\end{aligned}
$$

$$
\begin{aligned}
& \mathrm{l}=1 \quad \mathrm{p}=1
\end{aligned}
$$

H ere we denoted w ith the check on the rapidities the absence of the corresponding particle in them atrix elem ent. It is clear from the expressions ( $\overline{3}-9)$ and ( $\overline{3} \cdot 10$ ) that the only possible non-vanishing $m$ atrix elem ents $(\overline{3}, \overline{1} \overline{8})$ are those when $n+m$ is even. Taking $(3, \overline{1} 2)-(3, \overline{1} \overline{4})$ as the intial conditions for the recursive equations (3)-19) them iteratively or use ( 3.92 ) and evaluate the $m$ atrix elem ents directly. C losed solutions for these equations have been presented for the rst tim e in "in .
3.4 Free Ferm ion w ire w ith im purities

At this point we have to abandon the general discussion and consider a concrete theory, which for the reasons already explained we choose to be the com plex free Ferm ion. Then the generators of the $Z F$-algebra $Z_{i}() ; Z_{i}^{Y}()$ are just the usual creation and annihilation operators $a_{i}() ; a_{i}^{y}()$.
3.4.1 D efect m atrix elem ents

Let us now use ( 3.9 ) $-(3)=10$ ) in order to evaluate $m$ atrix elem ents involving the defect operator. In what follow $s$, the $m$ ost relevant $m$ atrix elem ents are those involving four particles, for which we com pute

$$
\begin{aligned}
& h a_{i}(1) a_{i}(2) Z \quad a_{j}^{y}(3) a_{j}^{y}(4) i={ }^{2} \hat{W}_{i}(1) \hat{W}_{i}(2){ }_{h}(13)(24)_{i j} ;
\end{aligned}
$$

w ith the abbreviations

$$
\begin{equation*}
\mathrm{w}_{\mathrm{i} \uparrow}(1 ; 2)={ }^{2} \hat{\mathrm{w}}_{\mathrm{i}}(1) \hat{\mathrm{w}} \hat{i}^{(2)} \text { and } \mathrm{k}_{\mathrm{ii}}(1 ; 2)={ }^{2} \hat{K}_{i}(1) \hat{K}_{i}(2): \tag{3.20}
\end{equation*}
$$

O ne can now try to nd solutions for alln-particle form factors either from $(3,18)-(3, \overline{1})$ or by direct com putation. For instance for the stated choice of particles involved, we com pute

$$
\begin{aligned}
& \operatorname{det}^{2 n}\left({ }_{1}::: 2 n ;{ }_{1}^{0}:::{ }_{2 n}^{0}\right) \operatorname{det}^{2 m}\left(2 n+1::: 2 n+2 m ; 1:::{ }_{2 m}\right) \\
& \mathrm{Y}^{\mathrm{k}} \\
& \hat{W}_{i}(2 p) \hat{W}_{i}\left(\begin{array}{ll}
2 p & 1
\end{array}\right)\left(\begin{array}{lll}
2 p & 2 n+2 p
\end{array}\right)\left(\begin{array}{lll}
2 p & 1 & 2 n+2 p
\end{array}\right) \\
& \mathrm{p}=1 \\
& Y^{n} \\
& \hat{K}_{i}(2 p)(2 p+2 p 1) \quad \hat{K}_{i}(2 p)(2 p+2 p 1) ;
\end{aligned}
$$

where A ` ( 1 :: : , ; ${ }_{1}^{0}::$ : ${ }^{0}$ ) is a rank ' $m$ atrix whose entries are given by

$$
\left.A_{i j}^{\prime}=\cos ^{2}\left[\begin{array}{ll}
(i & j
\end{array}\right)=2\right]\left(\begin{array}{ll}
i & 0  \tag{3,22}\\
j
\end{array}\right) ; \quad 1 \quad \text { i; } j \quad \text { : }
$$

The $m$ atrix elem ents are com puted sim ilarly as in [G] and references therein. Likew ise we com pute

$$
\begin{align*}
& \operatorname{det} \mathrm{B}^{\mathrm{n}}\left({ }_{\mathrm{n}}::: \mathrm{I}_{1} ; 1::: \mathrm{n}_{\mathrm{n}}\right) \operatorname{det} \mathrm{B}^{\mathrm{n}}\left(\mathrm{r}_{1}::: \mathrm{n}_{\mathrm{n}} ;{ }_{1}^{0}:::{ }_{\mathrm{n}}^{0}\right) \text {; }
\end{align*}
$$

where we introduced a new rank 'm atrix $B$ ` ( $1::$ : $;_{1}^{0}:$ : : ${ }^{0}$ ) whose entries are now sim ply given by

$$
B_{i j}^{\prime}=\left(\begin{array}{ll}
i & 0  \tag{3.24}\\
i
\end{array}\right) ; \quad 1 \quad \text { i; } j \quad \text { : }
$$


3.4.2 C onductance in the $\mathrm{T}=\mathrm{m}=0$ regim e

It is well-know $n$ that for a free Ferm ion theory (also for a single com plex free Ferm ion) the conform al U (1)-current-current correlation function is sim ply

$$
\begin{equation*}
h J(r) J(0) \dot{i}_{T=m=0}=\frac{1}{r^{2}}: \tag{325}
\end{equation*}
$$

This expression can also be obtained by using the expansion $[\underline{3}-2$, , together $w$ th the $m$ ass less prescription as outlined above and the expressions for the only non-vanishing form factors of the current operator in the com plex free Ferm ion theory

$$
\begin{equation*}
\mathrm{F}_{2}^{J j\{i}(; \sim)=\mathrm{F}_{2}^{J \ddot{\mu}\{ }(; \sim)=\quad \text { im } \mathrm{e}^{\frac{+\sim}{2}}: \tag{326}
\end{equation*}
$$

In particular, the $m$ assless lim it of the previous expressions gives, according to the $m$ assless prescription,
 and the problem is reduced to nd the Fourier transform of the function $r{ }^{2}$, which is given by $P^{R_{1}} d r e^{i!r_{r}}{ }^{2}=\quad$ ! for ! > 0 , w ith $P$ denoting the principle value. $T$ his yields in the absence of a defect $G(0)=1=2$, in com plete agreem ent $w$ ith the $w$ ell-know $n$ classical expression for the conductance in a w ire w ithout any im purities, see for instance [ī̄̄]

For them ore com plicated situation ofn defects $Z_{1} \quad n$ libcated in space at positions $y_{1}::: y_{n}, w e$ com pute in the zero tem perature and zero $m$ ass regim $e$
$h J(r) Z_{1}$

The functions $\hat{W}_{i}{ }^{R}(), \hat{K}_{i}{ }^{R}(),::$ de ned in $\left(\hat{3} \underline{2}^{-} \underline{2}^{9}\right)$ are the $m$ assless lim its of the corresponding functions $\hat{W}_{i}(), \hat{K}_{i}(),::$ For all the defects we considered, it tumed out that the rst contribution to the previous correlation function is actually vanishing, so that $\left.\left[3^{-2} \mathbf{2}^{-}\right)^{\prime}\right)$ is considerably simpli ed. In m any of the exam ples, this is due to the fact that the amplitudes $\hat{K}_{i}()$ are vanishing in the rst place, as a consequence of the cross-
 cases as a consequence of the parity of the function $\hat{K}_{i}()$. For instance, we nd that, for the energy operator defect such function, although initially non-vanishing, satis es $\hat{K}_{i}()=\hat{K}_{i}(\quad)$, such that $\lim _{m}!0_{1}^{R_{1}} d \hat{K}_{i}()=0$.
W e can now either use $(3-29)$ to com pute the conductance or evaluate the expression ( $3-8,0)$ directly in which the frequency lim it is already taken, in both cases we obtain

$$
\begin{equation*}
\left.G \quad(0)={\frac{1}{2(2)^{3}}}_{i \quad{ }_{i}}^{Z_{0}} d e w_{i f}^{\operatorname{RR}}[\ln (1) \quad e) ;\right]: \tag{3.30}
\end{equation*}
$$

There are, in addition, further generic results which can be obtained independently of the speci c form of the defect. W e present them at this stage and $w i l l$ con $m$ their validity below by som e speci c exam ples. Specializing to the case in which all ' defects are of the sam e type and equidistantly separated, i.e. $\mathrm{y}=\mathrm{y}_{1}=\quad \quad=\mathrm{W}$ e can identify two distinct regim es
where we used in addition (3,16). Supported by our explicit exam ples below, we nd that
 A s we have already argued above

$$
\begin{equation*}
\mathrm{k}_{\mathrm{ii}} \mathrm{RR}^{\mathrm{R}}(1 ; 2)=0: \tag{3.32}
\end{equation*}
$$

It will tum out, that the two regim es speci ed in (3) are also of a very distinct nature in the TBA context as presented in part II.
3.4.3 A w ire w ith im purities of energy operator type

Let us exem plify the working of the above form ulae with a concrete defect operator. A s a sim ple exam ple we choose the energy operator defect as presented in section 2.3.1. C onsidering rst a w ire possessing a single defect of this type, we com pute

$$
\begin{equation*}
\hat{W}_{i}()=\frac{4 \cos B \cosh { }^{2}}{\cosh 2+\cos 2 B} ; \quad \hat{K_{i}}()=\frac{2 i \sin B \sinh }{\sin B \cosh } ; \quad \mathrm{w}_{\mathrm{i} ;}^{\mathrm{RR}}(1 ; 2)=(2 \cos B)^{2} \tag{3.33}
\end{equation*}
$$

w ith B being the e ective coupling constant as de ned in the caption of gure 1 , such that

$$
\begin{equation*}
\left.h J(r) Z J(0) i_{T=m=0}=\frac{\cos ^{2} B}{r^{2}}=\right) \quad G \quad(0)=\frac{\cos ^{2} B}{2}: \tag{3.34}
\end{equation*}
$$

It will tum out that this is in com plete agreem ent $w$ ith the corresponding result from the Landauer form ula (1, (1)

P roceeding in the sam e way for a w ire w ith tw o or four im purities we evaluated [in in in the regim ey $r$

$$
\begin{align*}
\mathrm{hJ}(\mathrm{r}) \mathrm{Z}_{1} \mathrm{Z}_{2} \mathrm{~J}(0) \mathrm{i}_{\mathrm{T}=\mathrm{m}=0} & =\frac{41+\sin ^{4} \mathrm{~B}}{\mathrm{r}^{2}\left[\cos ^{2}(2 \mathrm{~B}) 3^{2}\right.} ;  \tag{3.35}\\
\mathrm{G}^{1{ }^{2}(0)} & =\frac{2 \sin ^{4} \mathrm{~B}}{\left[3 \cos ^{2}(2 \mathrm{~B})\right]^{2}} ;  \tag{3.36}\\
\mathrm{hJ}(\mathrm{r}) \mathrm{Z}_{1} \mathrm{Z}_{2} \mathrm{Z}_{3} \mathrm{Z}_{4} \mathrm{~J}(0) \mathrm{i}_{\mathrm{T}=\mathrm{m}=0} & =\frac{1}{2 \mathrm{r}^{2}} 1+\frac{\cos ^{8} \mathrm{~B}}{\left[\cos ^{4} \mathrm{~B} 2\left(1+\sin ^{2} \mathrm{~B}\right)^{2}\right]^{2}} ;  \tag{3.37}\\
\mathrm{G}^{123^{4}(0)} & \left.=\frac{1}{4} 1+\frac{\cos ^{8} \mathrm{~B}}{\left[\cos ^{4} \mathrm{~B}\right.} 2\left(1+\sin ^{2} \mathrm{~B}\right)^{2}\right]^{2} \tag{3.38}
\end{align*}:
$$

In the regim ey! 0, we obtained [ī]

$$
\begin{align*}
& \lim _{y!} h J(r) Z_{1} Z_{2} J(0) i_{T=m=0}=\frac{1}{r^{2}} \frac{\cos ^{4} B}{\left(1+\sin ^{2} B\right)^{2}} ;  \tag{3.39}\\
& \lim _{y!} G^{1}{ }^{2}(0)=\frac{1}{2} \frac{\cos ^{4} B}{\left(1+\sin ^{2} B\right)^{2}} \text {; }  \tag{3.40}\\
& \lim _{y!0} h J(r) Z_{1} Z_{2} Z_{3} Z_{4} J(0) i_{T=m=0}=\frac{1}{r^{2}} \frac{\cos ^{4} B}{\cos ^{4} B 2\left(1+\sin ^{2} B\right)^{2}} \quad \text {; }  \tag{3.41}\\
& \lim _{y!} G^{1} 2^{3}{ }^{4}(0)=\frac{1}{2} \frac{\cos ^{4} B}{\cos ^{4} B} 2\left(1+\sin ^{2} B\right)^{2} \quad 2 \quad: \tag{3.42}
\end{align*}
$$

It w illtum out that we can reproduce these expressions by evaluating the Landauer form ula (12) when computing the densities w ith the help of the TBA. This w ill now be outlined in part II together w th the general conclusions conceming also this part.

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[^0]:    ${ }^{2}$ D enoting by $s$ the Lorentz spin of the operator $O$ and being a constant, the form factors satisfy

    $$
    F_{n}^{\circ j_{1}::: n_{n}}\left(1+;::: ;_{n}+\right)=e^{s} F_{n}^{0 j_{1}::: n_{n}}\left(1 ;::: ;_{n}\right):
    $$

